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November 2014

FSA551 Dual SPST Depletion Mode Audio Switch

Features

- Dual SPST
- Depletion Mode Technology
- . -3 dB Bandwidth: 240 MHz
- V_{CC-OFF} : 1.5 V to 3.0 V
- V_{CC-ON}: 0 V to 0.2 V
- . V_{SW-OFF}: -0.3 V to 3 V
- V_{SW-ON}: -0.3 V to 3 V
- R_{ON}: 0.38 Ω Typical
- Ron Flat: 0.01 Ω (Typical)
- THD+N: 0.0005% (Typical)
- Fairchild Green, RoHS Compliant, Halogen Free

Description

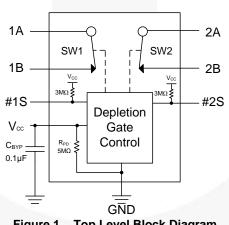
The FSA551 is a high-performance dual single-pole single-throw (SPST x 2) audio switch. The Depletion Mode technology allows the device to conduct signals when there is no V_{CC} available and to isolate signals when V_{cc} is present. During signal conduction, the Depletion Mode gate control allows the FSA551 to achieve excellent THD+N performance while consuming minimal power.

Related Resources

FSA551 Evaluation Board

Applications

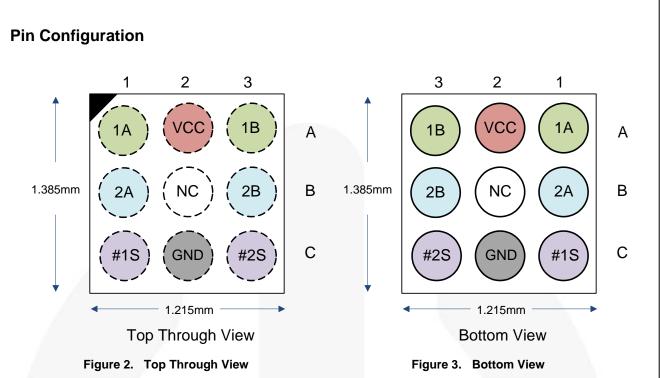
- Smart Phones
- Tablets, Ultra Books





Ordering Information

| Part Number | Operating Temperature Range | Top Mark | Package | Packing Method |
|-------------|--------------------------------|----------|---|------------------------------|
| FSA551UCX | -40 to 85°C | U9 | 9-Ball WLCSP, 0.40 mm Pitch, 1.215 x 1.385 x 0.58 mm (Nominal) | 3000 Units on Tape & Reel |



Pin Descriptions

| Pin # | Name | Туре | Description |
|-------|-----------------|---------------|---|
| A1 | 1A | Depletion I/O | A-Port of Switch 1 (Normally Closed) |
| A3 | 1B | Depletion I/O | B-Port of Switch 1 (Normally Closed) |
| C1 | #1S | Control | Select to Enable/Disable SW1 (Enable LOW) |
| A2 | V _{CC} | Power Supply | Power Supply Input |
| B2 | NC | No Connect | Do Not Connect |
| C2 | GND | Ground | Ground |
| B1 | 2A | Depletion I/O | A-Port of Switch 2 (Normally Closed) |
| B3 | 2B | Depletion I/O | B-Port of Switch 2 (Normally Closed) |
| C3 | #2S | Control | Select to Enable/Disable SW2 (Enable LOW) |

Table 1. Depletion Mode Control Truth Table

| V _{cc} | #1S | #2S | Switch 1 | Switch 2 |
|-----------------|------|------|----------|----------|
| LOW | Х | Х | ON | ON |
| HIGH | HIGH | HIGH | OFF | OFF |
| HIGH | LOW | HIGH | ON | OFF |
| HIGH | HIGH | LOW | OFF | ON |

Table 2. Recommended External Component

| Component | Description | Vendor | Parameter | Min. | Тур. | Unit |
|-----------|-------------------------------|-----------------------|-----------|------|------|------|
| CBYP | 0.1 μF, 10%, 6.3 V, X5R, 0201 | Murata GRM033R60J104K | С | 0.65 | 0.1 | μF |

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

| Symbol | Parameter | | Min. | Max. | Unit |
|-----------------------------|---|--|------|------|------|
| Vcc | Supply/Control Voltage | | -0.5 | 4.6 | V |
| V _{CNTRL} | Control Input Voltage | #1S, #2S | -0.5 | 4.6 | V |
| V _{SW(ON)} | DC Switch I/O Voltage (Switch Conducting) | 1A, 1B, 2A, 2B | -0.5 | 3.3 | V |
| $V_{\text{SW}(\text{OFF})}$ | DC Switch I/O Voltage (Switch Isolated) | 1A, 1B, 2A, 2B | -0.5 | 3.3 | V |
| I _{SW} | Switch I/O Current | V _{CC} =0 V (Switch Conducting) | | 350 | mA |
| ISWPEAK | Peak Switch Current | Pulsed at 1 ms Duration, <a><10% Duty Cycle | | 500 | mA |
| | Human Body Model, ANSI/ESDA/JEDEC | I/O Ports | | 7 | |
| | JS-001-2012 | All Other Pins | | 5 | |
| ESD | Charged Device Model, JEDEC: JESD22-C101 | | | 2 | kV |
| | | Contact | | 8 | |
| | IEC 61000-4-2 System | Air Gap | | 15 | |
| TA | Absolute Maximum Operating Temperature | | -40 | +85 | °C |
| Θ_{JA} | Thermal Resistance, Junction-to-Ambient | 2S2P JEDEC std. PCB | | 97 | °C/W |
| T _{STG} | Storage Temperature | | -65 | +150 | °C |

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding these ratings or designing to Absolute Maximum Ratings.

| Symbol | Parameter | | Min. | Max. | Unit |
|----------------------|--|---------------------------|------|------|------|
| V _{CC(ON)} | Supply Voltage with Depletion Switch Conducting (| (1A=1B; 2A=2B) | 0 | 0.2 | V |
| V _{CC(OFF)} | Supply Voltage with Depletion Switch Isolated (1Ar | ≠1B; 2A≠2B; #1S=#2S=HIGH) | 1.5 | 3.0 | V |
| V _{SW(ON)} | DC Switch I/O Voltage | Switch Conducting | -0.3 | 3.0 | V |
| V _{SW(OFF)} | DC Switch I/O Voltage | Switch Isolated | -0.3 | 3.0 | V |
| V _{CNTRL} | Control Input Voltage | #1S, #2S | 0 | 3.0 | V |

FSA551 — Dual SPST Depletion Mode Audio Switch

DC Electrical Characteristics

Unless otherwise specified, typical values are for $T_A=25^{\circ}C$.

| Symbol | Parameter | Condition | V _{cc} (V) | T _A =-4 | 0°C to | +85°C | Unit |
|-----------------------------|--|--|---------------------|--------------------|--------|-------|------|
| e ye i | | | | Min. | Тур. | Max. | • |
| $V_{\text{CC}(\text{HYS})}$ | Supply Voltage Hysteresis | | | | 450 | | mV |
| I _{ON} | Switch-to-GND Leakage Current (Switch Conducting) | 1A=2.6 V, 1B=Float, 2A=2.6 V, 2B=Float | 0 | | 0.1 | 5 | μA |
| I _{OFF} | Switch-to-GND Leakage Current (Switch Isolated) | 1A =2.6 V, 1B=GND, 2A=2.6 V, 2B=GND, #1S=#2S=V _{CC} | 1.8 | | 0.1 | 10 | μA |
| I _{CCT} | Increase in I _{CC} per Control Voltage | #1S or #2S=1.2 V | 3.0 | | 7 | 15 | μA |
| R _{ON} | Switch On Resistance | I_{SW} =100 mA, V_{SW} =-0.3 V to 3 V | 0 | | 0.38 | 0.60 | Ω |
| ΔR_{ON} | Switch On Resistance Difference, Channel to Channel | I_{SW} =100 mA, V_{SW} =-0.3 V to 3 V | 0 | | 0.01 | | Ω |
| R _{FLAT(ON)} | On Resistance Flatness | I_{SW} =100 mA, V_{SW} =-0.3 V to 3 V | 0 | | 0.01 | | Ω |
| R _{PD} | V _{CC} Pull-Down Resistance | | <0.2 | | 5.0 | | MΩ |
| R _{PU} | Control Pull-Up Resistance | | <0.2 | | 3.0 | | MΩ |
| | Outland and Sumply Current | Switch Isolated, #1S=#2S=V _{CC} | 1.5 - 3.0 | | 70 | 120 | |
| Icc | Quiescent Supply Current | Switch On | 0.2 | | 0.1 | 0.5 | μA |
| VIH | Select Pin Input High Voltage | | 1.5 – 3.0 | 1.2 | | | V |
| VIL | Select Pin Input Low Voltage | | 1.5 – 3.0 | | | 0.55 | V |

AC Electrical Characteristics

Unless otherwise specified, typical values are for $T_A=25^{\circ}C$.

| Symbol | Deremeter | Condition | | T _A =- 40°C to +85°C | | +85°C | Uni |
|-------------------|---|--|-----------------------|---------------------------------|--------|-------|-----|
| Symbol | Parameter | Condition | V _{cc} (V) | Min. | Тур. | Max. | t |
| t _{ON} | Turn-On Time V _{CC} to Output | $R_L=2 \text{ k}\Omega$, $C_L=10 \text{ pF}$, $V_{SW}=3 \text{ V}$, (Measured 90/10%), Figure 5 | 1.8 → 0 | | 445 | | μs |
| toff | Turn-Off Time V _{CC} to Output | $R_L=2 k\Omega$, $C_L=10 pF$, $V_{SW}=3 V$, (Measured 90/10%), Figure 5 | 0 → 1.8 | | 175 | | μs |
| t _{ONS} | Turn-On Time Control Pin | nA=2 kΩ to 2.85 V, nB=1 Ω//10 pF to GND, $\#_n$ S= 1.8 \rightarrow 0 V, (Measured 20/80%), Figure 5 | 1.8 | | 205 | | μs |
| toffs | Turn-Off Time Control Pin | nA=2 kΩ to 2.85 V, nB=1 Ω//10 pF to GND, #nS= 0 → 1.8 V, (Measured 20/80%), Figure 4, Figure 5 | 1.8 | | 29 | | μs |
| Oirra | Port A Off Isolation | $_{n}A=2 k\Omega$ to GND, $_{n}B=1 \Omega$ to GND, # $_{n}S=V_{CC}$, Port B V _{SW} =600 mV _{PP} Ground Referenced, (Measure at f=20 kHz), Figure 7 | 1.8 | | -75 | | dB |
| O _{IRRB} | Port B Off Isolation | $_{n}A=2 k\Omega$ to 2.85 V, $_{n}B=1 \Omega$ to GND, $\#_{n}S=V_{CC}$, Port A V _{DC} + 300 mV _{PP(AC)} , (Measure at f=20 kHz), Figure 6 | 1.8 | | -100 | | dB |
| BW | -3dB Bandwidth | $R_L=2 k\Omega, C_L=0 pF$ | 0 | | 240 | | MHz |
| THD+N | Total Harmonic Distortion + Noise | $R_L=2 k\Omega$, f=20 Hz to 20 kHz, DC Bias=0 V, V _{SW} =600 mV _{PP} , Measurement BW < 22 kHz | 0 | | 0.0005 | | % |

Capacitance

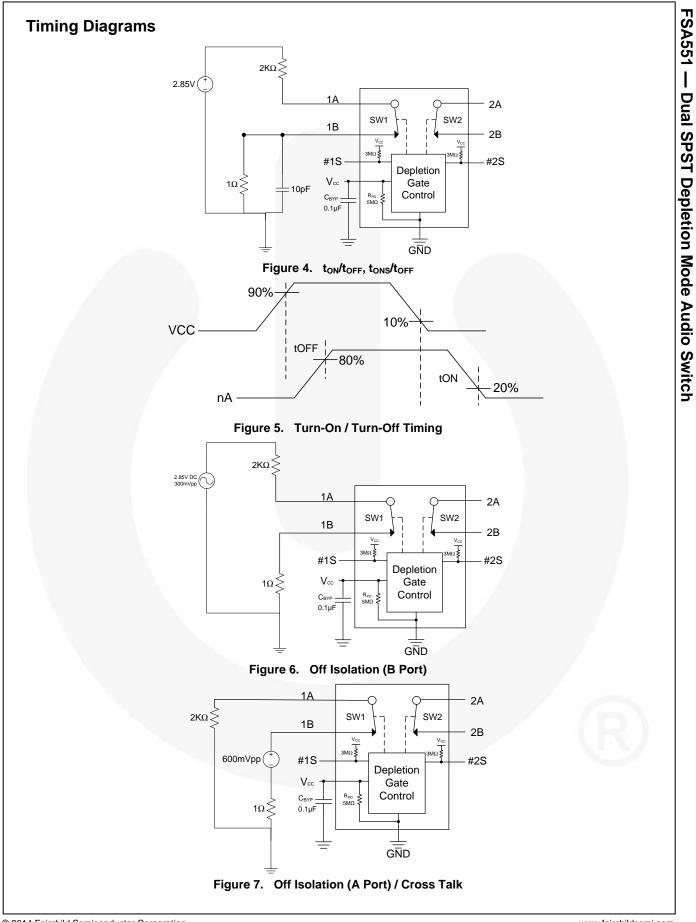
| Symbol | Parameter | Condition | | Т | = +25° | С | Unit |
|-------------------|-------------------------|---|---------------------|------|--------|------|------|
| Symbol | Farameter | Condition | V _{cc} (V) | Min. | Тур. | Max. | Unit |
| Con | On Capacitance | f=1 MHz, 400 mV _{PP} , 1A, 1B, 2A, 2B | 0 | | 21 | | pF |
| C _{OFF} | Off Capacitance | f=1 MHz, 400 mV _{PP} , 1A, 1B, 2A, 2B, #1S=#2S=V _{CC} | 1.8 | | 25 | / | pF |
| C _{CTRL} | Control Pin Capacitance | f=1 MHz, 400 mV _{PP} , #1S, #2S | 1.8 | | 2.5 | | pF |

Oscillator Frequency

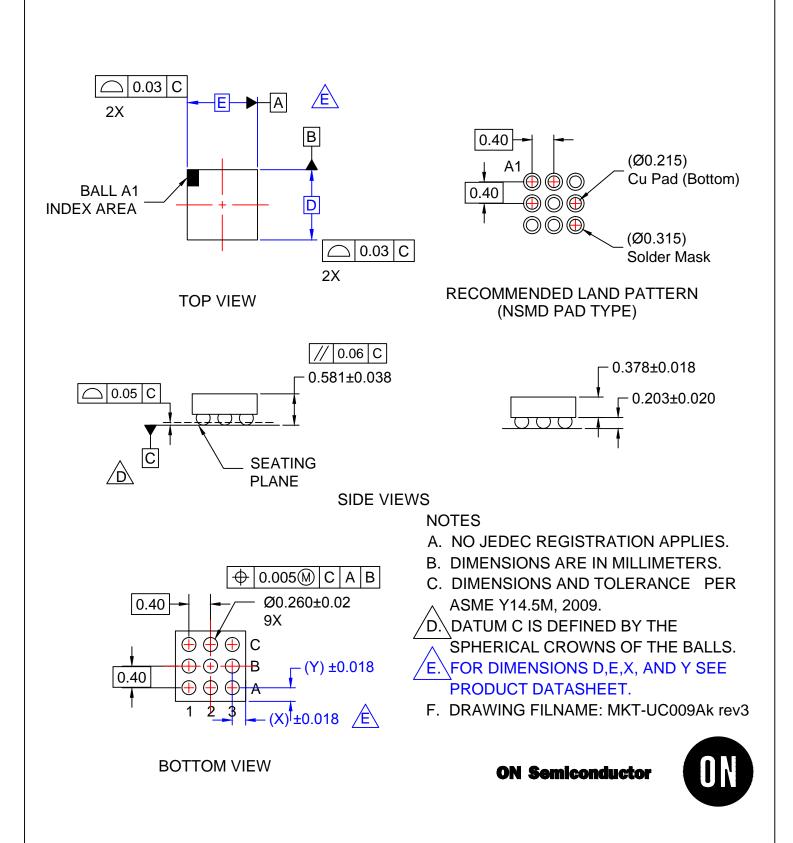
| Symbol Parameter | Beremeter | Condition Vcc (V) | | / | T _A = +25 | °C | Unit |
|-------------------|---|--------------------|-----------------------|------|----------------------|------|------|
| | Farameter | Condition | • V _{cc} (V) | Min. | Тур. | Max. | Unit |
| fosc | Oscillator Frequency ⁽¹⁾ | Oscillator Enabled | 1.8 | | 775 | | kHz |
| f _{OSC%} | Oscillator Frequency Tolerance Over Process & Temperature ⁽¹⁾ | Oscillator Enabled | 1.8 | | | 30 | % |

Note:

1. Parameters guaranteed by Design and Characterization.



| E | D | Х | Y |
|--------------|--------------|-----------|-----------|
| 1.215±.03 mm | 1.385±.03 mm | 0.2075 mm | 0.2925 mm |
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